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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



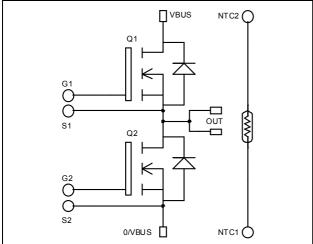






Phase leg **MOSFET Power Module**

 $V_{DSS} = 100V$ $I_D = 278A$ @ Tc = 25°C



G2 🛭 OUT S2 🛭 O/VBUS оит І S2 0 NTC2 G2 **f** NTC1 1

Application

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

Features

- Power MOS V® FREDFETs
 - $Low \; R_{DSon}$
 - Low input and Miller capacitance
 - Low gate charge
 - Fast intrinsic reverse diode
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- **RoHS Compliant**

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		100	V
I_D	Continuous Drain Current $ T_c = 25^{\circ}C $ $T_c = 80^{\circ}C $		278 207	A
I_{DM}	Pulsed Drain current			11
V_{GS}	Gate - Source Voltage		±30	V
R _{DSon}	Drain - Source ON Resistance		5	mΩ
P_{D}	Maximum Power Dissipation $T_c = 25$ °C		780	W
I_{AR}	Avalanche current (repetitive and non repetitive)		100	A
E_{AR}	Repetitive Avalanche Energy		50	mJ
E_{AS}	Single Pulse Avalanche Energy	he Energy		1113

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
T	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 100V$	$T_j = 25^{\circ}C$			200	μΑ
$I_{ m DSS}$		$V_{GS} = 0V, V_{DS} = 80V$	$T_j = 125$ °C			1000	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 125A$			4.5	5	mΩ
V _{GS(th)}	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 5mA$		2		4	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{V}$				±200	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		20		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		8		nF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		2.9		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		700		
Q_{gs}	Gate – Source Charge	$V_{\text{Bus}} = 50V$		120		nC
Q_{gd}	Gate – Drain Charge	$I_D = 250A$		360		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		80		ma
$T_{\rm r}$	Rise Time	$V_{GS} = 15V$ $V_{Bus} = 66V$		165		
$T_{d(off)}$	Turn-off Delay Time	$I_{\rm D} = 250 A$		280		ns
T_{f}	Fall Time	$R_G = 2.5 \Omega$		135		
E_{on}	Turn-on Switching Energy	Inductive switching @ 25°C		1.1		Т
E _{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 250A, R_G = 2.5\Omega$		1.2		mJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		1.22		T
E _{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 250A, R_G = 2.5\Omega$		1.28		mJ

Source - Drain diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_{S}	Continuous Source current		$Tc = 25^{\circ}C$			278	Α
	(Body diode)		$Tc = 80^{\circ}C$			207	A
V_{SD}	Diode Forward Voltage	$V_{GS} = 0V, I_S = -250A$				1.3	V
dv/dt	Peak Diode Recovery					5	V/ns
t _{rr}	Reverse Recovery Time		$T_j = 25$ °C			190	ns
·rr	Reverse receivery Time	$I_S = -250A$ $V_R = 50V$	$T_j = 125$ °C			370	113
Qrr	Reverse Recovery Charge	$di_{S}/dt = 200A/\mu s$	$T_j = 25^{\circ}C$		0.8		uС
			$T_{j} = 125^{\circ}C$		3.4		μ

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

 $I_S \leq \text{- }278A \qquad \text{di/dt} \leq 200 \text{A/}\mu \text{s} \qquad V_R \leq V_{DSS} \qquad T_j \leq 150^{\circ}\text{C}$



Thermal and package characteristics

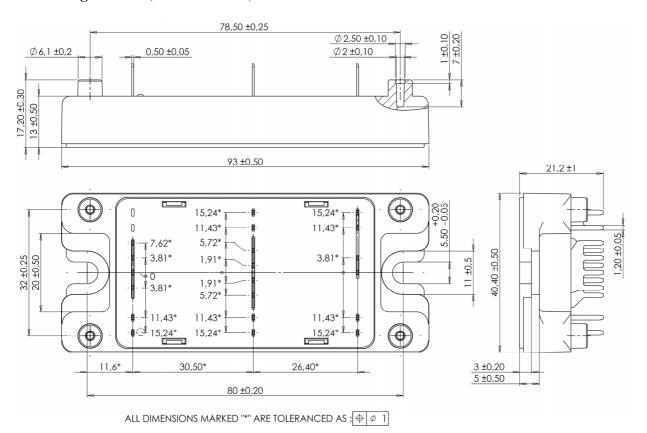
Symbol	Characteristic			Min	Typ	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance					0.16	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To Heatsink	M5	2.5		4.7	N.m
Wt	Package Weight				160	g	

Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C		50		kΩ
B 25/85	$T_{25} = 298.15 \text{ K}$		3952		K

$$R_T = \frac{R_{25}}{\exp \left[B_{25/85} \left(\frac{1}{T_{25}} - \frac{1}{T} \right) \right]}$$
 T: Thermistor temperature R_T: Thermistor value at T

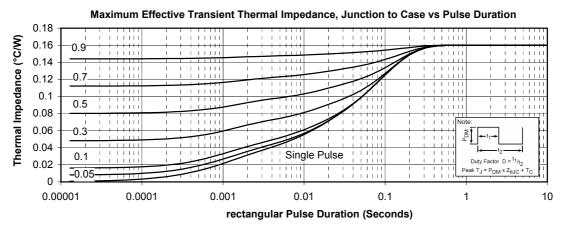
SP4 Package outline (dimensions in mm)

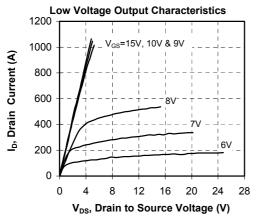


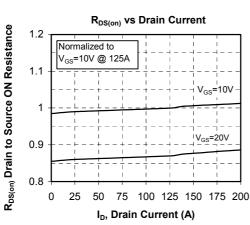
See application note APT0501 - Mounting Instructions for SP4 Power Modules on www.microsemi.com

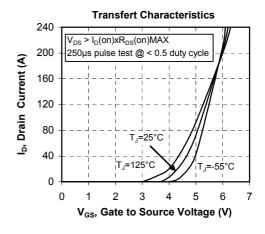


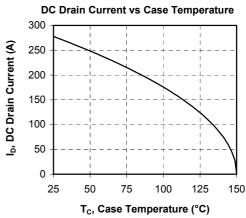
Typical Performance Curve



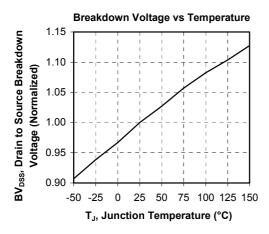


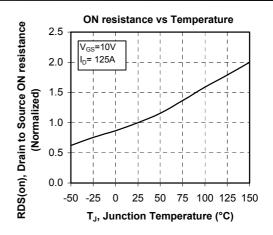


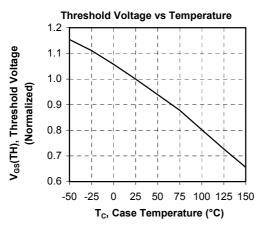


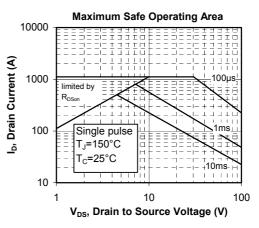


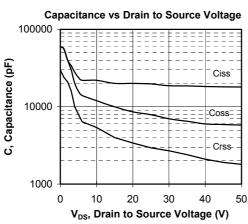


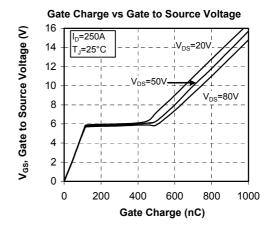




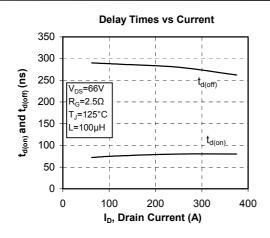


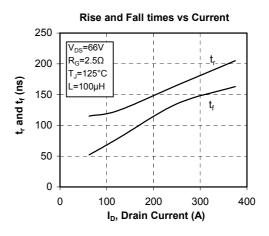


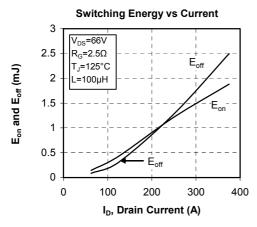


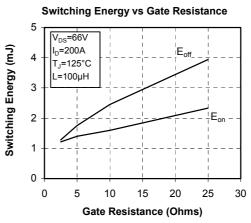


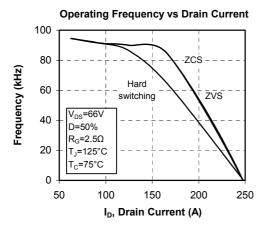


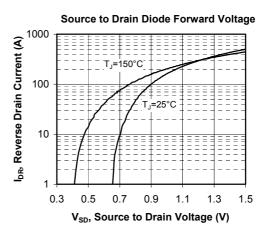












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